



TSB58T100S(A)S-255A

3A/100V⁽¹⁾, low VF Schottky barrier diode with trench MOS structure

ttB10.44 Tm 0 g 0 G [()] TJ E51

Mechanical Data

Chip Drawing	Item	Information
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Die Size (A)

1473 μ m

58 mil

